

#### FACTORY-PROGRAMMABLE ANY-FREQUENCY CMOS CLOCK GENERATOR + PLL

#### **Features**

- Generates up to 8 non-integer frequencies from 8 kHz to 125 MHz
- Exact frequency synthesis at each output (0 ppm error)
- Glitchless frequency changes
- Low output period jitter: 100 ps pp
- Configurable Spread Spectrum selectable at each output
- User-configurable control pins:
  - Output Enable (OEB\_0/1/2)
  - Power Down (PDN)
  - Frequency Select (FS\_0/1)
  - Spread Spectrum Enable (SSEN)
  - Loss of Lock Status (LOL)

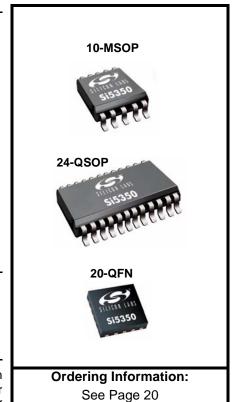
- Operates from a low-cost, fixed frequency crystal: 25 or 27 MHz
- Separate voltage supply pins:
  - Core VDD: 2.5 V or 3.3 V
  - Output VDDO: 2.5 V or 3.3 V
- Excellent PSRR eliminates external power supply filtering
- Very low power consumption (<15 mA)</li>
- Available in 3 packages types:
  - 10-MSOP: 3 outputs
  - 24-QSOP: 8 outputs
  - 20-QFN (4x4 mm): 8 outputs

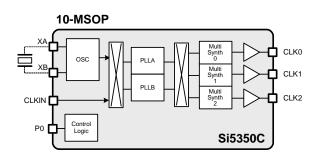
### **Applications**

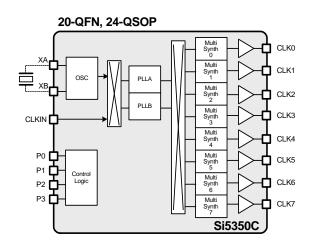
- HDTV, DVD/Blu-ray, set-top box
- Audio/video equipment, gaming
- Printers, scanners, projectors
- Residential gateways
- Networking/communication
- Servers, storage

### **Description**

The Si5350C generates free-running and/or synchronized clocks selectable on each of its outputs. A dual PLL + high resolution MultiSynth<sup>TM</sup> fractional divider architecture enables this user-definable custom timing device to generate any of the specified output frequencies at any of its outputs. This allows the Si5350C to replace a combination of crystals, crystal oscillators, and synchronized clocks (PLL). Custom pin-controlled Si5350C devices are requested using the ClockBuilder web-based part number utility (www.silabs.com/ClockBuilder).









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## 1. Electrical Specifications

**Table 1. Recommended Operating Conditions** 

 $(V_{DD} = 2.5 \text{ V } \pm 10\%, \text{ or } 3.3 \text{ V } \pm 10\%, T_A = -40 \text{ to } 85^{\circ}\text{C})$ 

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Ambient Temperature	T <sub>A</sub>		-40	25	85	°C
Cara Supply Valtage	V <sub>DD</sub>		2.97	3.3	3.63	V
Core Supply Voltage			2.25	2.5	2.75	V
Output Puffor Voltage	V		2.97	3.3	3.63	V
Output Buffer Voltage	$V_{DDOx}$		2.25	2.5	2.75	V

**Note:** All minimum and maximum specifications are guaranteed and apply across the recommended operating conditions. Typical values apply at nominal supply voltages and an operating temperature of 25 °C unless otherwise noted.

**Table 2. Absolute Maximum Ratings** 

Parameter	Symbol	Test Condition	Value	Unit
DC Supply Voltage	V <sub>DD_max</sub>		-0.5 to 3.8	V
	VIN_P1-3	Pins P1, P2, P3	-0.5 to 3.8	V
Input Voltage	VIN_P0	P0	-0.5 to (VDD+0.3)	V
	VIN_XA/B	Pins XA, XB	–0.5 to 1.3 V	V
Storage Temperature Range	TSTG		-55 to 150	°C
Operating Junction Temperature	T <sub>JCT</sub>		-55 to 150	°C

**Note:** Permanent device damage may occur if the absolute maximum ratings are exceeded. Functional operation should be restricted to the conditions specified in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Table 3. DC Characteristics** 

 $(V_{DD} = 2.5 \text{ V} \pm 10\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 \text{ °C})$ 

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
		Enabled 3 outputs	_	20	26	mA
Core Supply Current	I <sub>DD</sub>	Enabled 8 outputs	_	25	38	mA
		Power Down (PDN = V <sub>DD</sub> )	_	50	_	μΑ
Output Buffer Supply Current	I <sub>DDOx</sub>	C <sub>L</sub> = 5 pF	_	2.5	4	mA
Input Current	I <sub>P1-P3</sub>	Pins P1, P2, P3 Vin < 3.6 V	_	_	10	μΑ
	I <sub>P0</sub>	Pin P0	_	_	30	μΑ



**Table 4. AC Characteristics** 

 $(V_{DD} = 2.5 \text{ V } \pm 10\%, \text{ or } 3.3 \text{ V } \pm 10\%, T_A = -40 \text{ to } 85^{\circ}\text{C})$ 

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Power-up Time	T <sub>RDY</sub>	From $V_{DD} = V_{DDmin}$ to valid output clock, $C_L = 15$ pF, $f_{CLKn} > 1$ MHz	_	1	10	ms
Output Enable Time	T <sub>OE</sub>	From OEB assertion to valid clock output, C <sub>L</sub> = 15 pF, f <sub>CLKn</sub> > 1 MHz		_	10	μs
Output Frequency Transition Time	T <sub>FREQ</sub>	Time to settle to within ± 20 ppm of specified frequency upon change in frequency plan via FS pin, f <sub>CLKn</sub> > 1 MHz	_	100	_	μs
Minimum Pulse Width	T <sub>PW_PDN</sub>	Power down pin (PDN)	100	_	_	ms
Willimian Fuise Width	T <sub>PW_P0-3</sub>	Control pin (P0-P3)	200	_	_	ns
Spread Spectrum Frequency Deviation	SS <sub>DEV</sub>	Down Spread	-0.5	_	-2.5	%
Spread Spectrum Modulation Rate	SS <sub>MOD_C</sub>		30	31.5	33	kHz

## **Table 5. Thermal Characteristics**

Parameter	Symbol	Test Condition	Package	Value	Unit
			10-MSOP	131	°C/W
Thermal Resistance Junction to Ambient	$\theta_{JA}$	Still Air	24-QSOP	80	°C/W
			20-QFN	51	°C/W
		Still Air	10-MSOP	43	°C/W
Thermal Resistance Junction to Case	$\theta_{\sf JC}$		24-QSOP	31	°C/W
			20-QFN	16	°C/W



## **Table 6. Input Characteristics**

 $(V_{DD} = 2.5 \text{ V} \pm 10\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 \text{ °C})$ 

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Crystal Frequency	f <sub>XTAL</sub>		25	_	27	MHz
P0-P3 Input Low Voltage	V <sub>IL_P0-3</sub>		-0.1	_	0.3 x V <sub>DD</sub>	V
P0-P3 Input High Voltage	V <sub>IH_P0-3</sub>		0.7 x V <sub>DD</sub>	_	3.63	V
CLKIN Frequency Range	f <sub>CLKIN</sub>		10	_	100	MHz
CLKIN Input Low Voltage	V <sub>IL_CLKIN</sub>		-0.1	_	0.3 x V <sub>DD</sub>	V
CLKIN Input High Voltage	V <sub>IH_CLKIN</sub>		0.7 x V <sub>DD</sub>	_	3.63	V

Table 7. Output Characteristics ( $V_{DD}$  = 2.5 V ±10%, or 3.3 V ±10%,  $T_A$  = -40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Frequency Range	F <sub>CLK</sub>		0.008	_	133	MHz
Load Capacitance	C <sub>L</sub>	F <sub>CLK</sub> < 100 MHz	_	_	15	pF
Duty Cycle	DC	Measured at V <sub>DD</sub> /2	45	50	55	%
Rise/Fall Time	t <sub>r</sub> /t <sub>f</sub>	20%–80%, C <sub>L</sub> = 5 pF	0.6	1	1.3	ns
Output High Voltage	V <sub>OH</sub>	C <sub>1</sub> = 5 pF	V <sub>DD</sub> – 0.6	_	_	V
Output Low Voltage	V <sub>OL</sub>	OL = 3 βι	_	_	0.6	V
Period Jitter	J <sub>PER</sub>	Measured over 10k cycles	_	35	100	ps pk-pk
Cycle-to-Cycle Jitter	J <sub>CC</sub>	Measured over 10k cycles	_	30	90	ps pk-pk
RMS Jitter	J <sub>RMS</sub>	12 kHz-20 MHz	_	3.5	11	ps

Table 8. 25 MHz Crystal Requirements<sup>1,2</sup>

Parameter	Symbol	Min	Тур	Max	Unit
Crystal Frequency	f <sub>XTAL</sub>	_	25	_	MHz
Load Capacitance	C <sub>L</sub>	6	_	12	pF
Equivalent Series Resistance	r <sub>ESR</sub>	_	_	150	Ω
Crystal Max Drive Level	d <sub>L</sub>	_	_	100	μW

#### Notes:

- 1. Crystals which require load capacitances of 6, 8, or 10 pF should use the device's internal load capacitance for optimum performance. See register 183 bits 7:6. A crystal with a 12 pF load capacitance requirement should use a combination of the internal 10 pF load capacitors in addition to external 2 pF load capacitors.
- 2. Refer to "AN551: Crystal Selection Guide" for more details.

## Table 9. 27 MHz Crystal Requirements<sup>1,2</sup>

Parameter	Symbol	Min	Тур	Max	Unit
Crystal Frequency	f <sub>XTAL</sub>	_	27	_	MHz
Load Capacitance	C <sub>L</sub>	6	_	12	pF
Equivalent Series Resistance	r <sub>ESR</sub>	_	_	150	Ω
Crystal Max Drive Level	d <sub>L</sub>	_	_	100	μW

#### Notes:

- 1. Crystals which require load capacitances of 6, 8, or 10 pF should use the device's internal load capacitance for optimum performance. See register 183 bits 7:6. A crystal with a 12 pF load capacitance requirement should use a combination of the internal 10 pF load capacitors in addition to external 2 pF load capacitors.
- 2. Refer to "AN551: Crystal Selection Guide" for more details.



## 2. Typical Application

The Si5350C is a clock generation device that provides both synchronous and free-running clocks for applications where power, board size, and cost are critical. An example application is shown in Figure 1. Any other combination is possible.

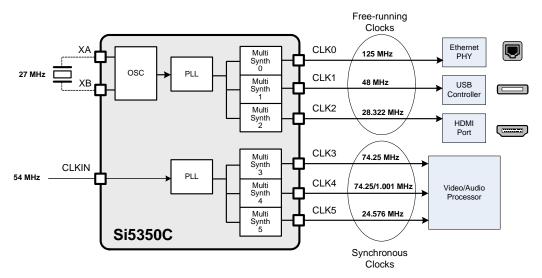


Figure 1. Replacing multiple XTAL/XOs and PLLs with one Si5350C



## 3. Functional Description

The architecture of the Si5350C generates of up to eight non-integer-related frequencies in any combination of free-running and/or synchronous clocks. A block diagram of both the 3-output and the 8-output versions are shown in Figure 2. Free-running clocks are generated using the on-chip oscillator + PLL, and the clock input pin (CLKIN) provides an external input reference for the synchronous clocks. Each MultiSynth<sup>TM</sup> is configurable with two frequencies (F1\_x, F2\_x). This allows a pin controlled glitchless frequency change at each output (CLK0 to CLK5).

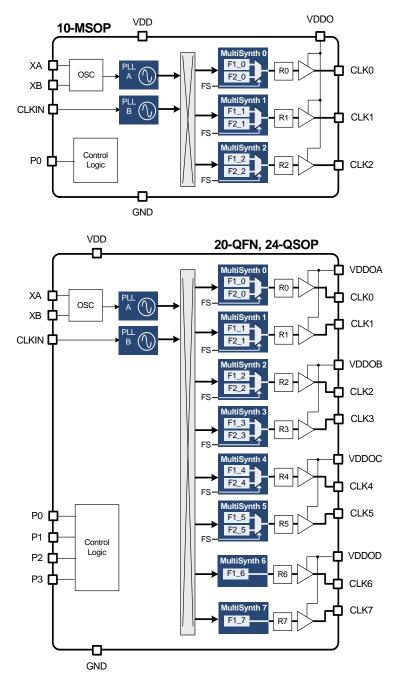


Figure 2. Block Diagrams of the Si5350C Devices with 3 and 8 outputs



## 4. Configuring the Si5350C

The Si5350C is a factory-programmed custom clock generator that is user definable with a simple to use web-based utility (www.silabs.com/ClockBuilder). The ClockBuilder utility provides a simple graphical interface that allows the user to enter input and output frequencies along with other custom features as described in the following sections. All synthesis calculations are automatically performed by ClockBuilder to ensure an optimum configuration. A unique part number is assigned to each custom configuration. Samples of any custom Si5350C factory-programmed clock generator are available with short lead times.

## 4.1. Crystal Inputs (XA, XB)

The Si5350C uses an optional fixed-frequency non-pullable standard AT-cut crystal as a reference to generate free-running output clocks. Note that a XTAL is not required for generating synchronous clocks that are locked to CLKIN.

#### 4.1.1. Crystal Frequency

The Si5350C can operate using either a 25 MHz or a 27 MHz crystal.

#### 4.1.2. Internal XTAL Load Capacitors

Internal load capacitors (C<sub>L</sub>) are provided to eliminate the need for external components when connecting a XTAL to the Si5350C. Options for internal load capacitors are 6, 8, or 10 pF, or no internal load capacitors. XTALs with alternate load capacitance requirements are supported using external load capacitors as shown in Figure 3.

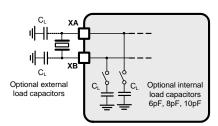


Figure 3. External XTAL with Optional Load Capacitors

## 4.2. External Clock Input Pin (CLKIN)

The external clock input is used as a reference for generating synchronous clocks. The input frequency can be specified from 10 to 100 MHz including fractional frequencies (e.g., 74.25 MHz x 1000/1001). The ClockBuilder utility automatically determines the exact synthesis ratio to guarantee an output frequency with 0 ppm error with respect to its reference.

## 4.3. Output Clocks (CLK0-CLK7)

The Si5350C is orderable as a 3-output (10-MSOP) or 8-output (24-QSOP, 20-QFN) clock generator. Output clocks CLK0 to CLK5 can be ordered with two clock frequencies (F1\_x, F2\_x) which are selectable with the optional frequency select pins (FS0/1). See "4.4.2. Frequency Select (FS\_0, FS\_1)" for more details on the operation of the frequency select pins. Each output clock can select its reference for either of the PLLs.

#### 4.3.1. Output Clock Frequency

Outputs can be configured at any frequency from 8 kHz up to 100 MHz. In addition, the device can generate any two non-integer related frequencies up to 125 MHz.

#### 4.3.2. .Spread Spectrum

Spread spectrum can be enabled on any of the clock outputs that use PLL\_B as its reference. Spread spectrum is useful for reducing electromagnetic interference (EMI). Enabling spread spectrum on an output clock modulates its frequency, which effectively reduces the overall amplitude of its radiated energy. Up to –15 dB reduction in EMI is possible.

The Si5350C supports several levels of spread spectrum allowing the designer to chose an ideal compromise

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between system performance and EMI compliance. The amount of spread is configurable within the following parameters:

■ Down spread: -0.5 to -2.5% modulation amplitude

An optional spread spectrum enable pin (SSEN) is configurable to enable or disable the spread spectrum feature. See "4.4.1. Spread Spectrum Enable (SSEN)" for details.

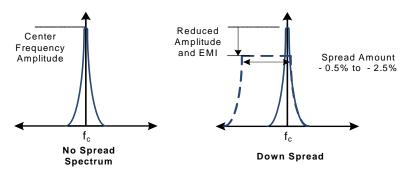


Figure 4. Available Spread Spectrum Profiles

#### 4.3.3. Invert/Non-Invert

By default, each of the output clocks are generated in phase (non-inverted) with respect to each other. An option to invert any of the clock outputs is also available.

#### 4.3.4. Output State When Disabled

There are up to three output enable pins configurable on the Si5350C as described in "4.4.5. Loss Of Lock (LOL)". The output state when disabled for each of the outputs is configurable as one of the following: disable low, disable high, or disable in high-impedance.

#### 4.3.5. Powering Down Unused Outputs

Unused clock outputs can be completely powered down to conserve power.

### 4.4. Programmable Control Pins (P0-P3) Options

Up to four programmable control pins (P0-P3) are configurable allowing direct pin control of the following features:

#### 4.4.1. Spread Spectrum Enable (SSEN)

An optional control pin allows disabling the spread spectrum feature for all outputs that were configured with spread spectrum enabled. Hold SSEN low to disable spread spectrum. The SSEN pin provides a convenient method of evaluating the effect of using spread spectrum clocks during EMI compliance testing.

#### 4.4.2. Frequency Select (FS 0, FS 1)

The Si5350C offers the option of configuring up to two frequencies per clock output (CLK0-CLK5) for either freerunning or synchronous clocks. This is a useful feature for applications that need to support more than one freerunning or synchronous clock rate on the same output. An example of this is shown in Figure 5. The FS pins select which frequency is generated from the clock output. In this example FS0 select the output frequency on CLK0, and FS1 selects the frequency on CLK1.



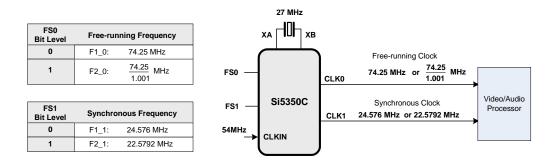


Figure 5. Example of Generating Two Clock Frequencies from the Same Clock Output

Up to two frequency select pins are available on the Si5350C. Each of the frequency select pins can be linked to any of the clock outputs as shown in Figure 6. For example, FS\_0 can be linked to control clock frequency selection on CLK0, CLK3, and CLK5; FS\_1 can be used to control clock frequency selection on CLK1, CLK2, and CLK4. Any other combination is also possible.

The Si5350C uses control circuitry to ensure that frequency changes are glitchless. This ensures that the clock always completes its last cycle before starting a new clock cycle of a different frequency.

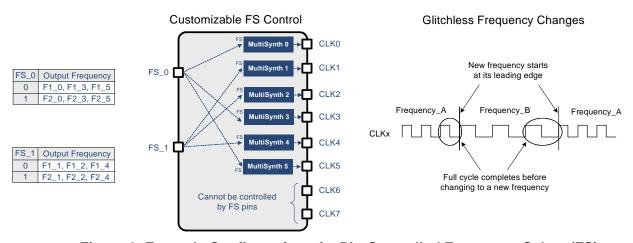


Figure 6. Example Configuration of a Pin-Controlled Frequency Select (FS)

#### 4.4.3. Output Enable (OEB\_0, OEB\_1, OEB\_2)

Up to three output enable pins (OEB\_0/1/2) are available on the Si5350C. Similar to the FS pins, each OEB pin can be linked to any of the output clocks. In the example shown in Figure 7, OEB\_0 is linked to control CLK0, CLK3, and CLK5; OEB\_1 is linked to control CLK6 and CLK7, and OEB\_2 is linked to control CLK1, CLK2, CLK4, and CLK5. Any other combination is also possible. If more than one OEB pin is linked to the same CLK output, the pin forcing a disable state will be dominant. Clock outputs are enabled when the OEB pin is held low.

The output enable control circuitry ensures glitchless operation by starting the output clock cycle on the first leading edge after OEB is asserted (OEB = low). When OEB is released (OEB = high), the clock is allowed to complete its full clock cycle before going into a disabled state. This is shown in Figure 7. When disabled, the output state is configurable as disabled high, disabled low, or disabled in high-impedance.



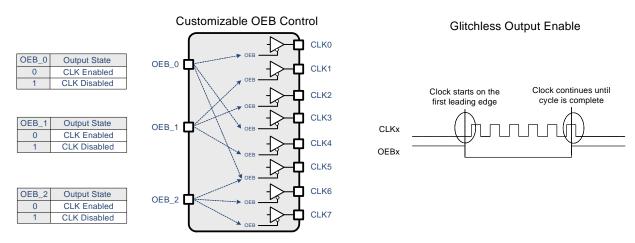


Figure 7. Example Configuration of a Pin-Controlled Output Enable

## Si5350C

#### 4.4.4. Power Down (PDN)

An optional power down control pin allows a full shutdown of the Si5350C to minimize power consumption when its output clocks are not being used. The Si5350C is in normal operation when the PDN pin is held low and is in power down mode when held high. Power consumption when the device is in power down mode is indicated in Table 3 on page 4.

#### 4.4.5. Loss Of Lock (LOL)

A loss of lock pin (LOL) is available to indicate the status of the synchronous clock outputs. The LOL pin is set to a low state when the synchronous clock outputs are locked to the clock input (CLKIN). This is the normal operating state for the synchronous clocks. The LOL pin will go high when the reference clock at the CLKIN input is removed or if its frequency deviates by more than 2000 ppm from its defined center frequency. In this case, the synchronous clocks will continue to free-run. An option to disable the synchronous output clocks during an LOL condition (LOL pin = high) is available. This only affects the clock outputs that were designated as synchronous clock outputs.

### 4.5. Design Considerations

The Si5350C is a self-contained clock generator that requires very few external components. The following general guidelines are recommended to ensure optimum performance.

#### 4.5.1. Power Supply Decoupling/Filtering

The Si5350C has built-in power supply filtering circuitry to help keep the number of external components to a minimum. All that is recommended is one 0.1 µF decoupling capacitor per power supply pin. This capacitor should be mounted as close to the VDD and VDDO pins as possible without using vias.

#### 4.5.2. Power Supply Sequencing

The VDD and VDDOx (i.e., VDDO0, VDDO1, VDDO2, VDDO3) power supply pins have been separated to allow flexibility in output signal levels. It is important that power is applied to all supply pins (VDD, VDDOx) at the same time. Unused VDDOx pins should be tied to VDD.

#### 4.5.3. External Crystal

The external crystal should be mounted as close to the pins as possible using short PCB traces. The XA and XB traces should be kept away from other high-speed signal traces. See "AN551: Crystal Selection Guide" for more details.

#### 4.5.4. External Crystal Load Capacitors

The Si5350C provides the option of using internal and external crystal load capacitors. If external load capacitors are used, they should be placed as close to the XA/XB pads as possible. See "AN551: Crystal Selection Guide" for more details.

#### 4.5.5. Unused Pins

Unused control pins (P0-P3) should be tied to GND.

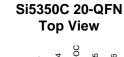
Unused CLKIN pin should be tied to GND.

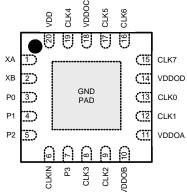
Unused XA/XB pins should be tied to GND.

Unused output pins (CLK0–CLK7) should be left unconnected.

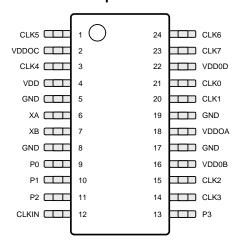


## 5. Pin Descriptions (20-QFN, 24-QSOP)





## Si5350C 24-QSOP Top View



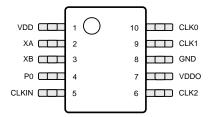
Pin Name	Pin N	umber	Pin Type	Function	
riii Naiile	20-QFN	24-QSOP	гііі туре	Fullction	
XA	1	6	I	Input pin for external XTAL	
XB	2	7	I	Input pin for external XTAL	
CLKIN	6	12	I	External reference clock input	
CLK0	13	21	0	Output clock 0	
CLK1	12	20	0	Output clock 1	
CLK2	9	15	0	Output clock 2	
CLK3	8	14	0	Output clock 3	
CLK4	19	3	0	Output clock 4	
CLK5	17	1	0	Output clock 5	
CLK6	16	24	0	Output clock 6	
CLK7	15	23	0	Output clock 7	
P0	3	9	I	User configurable input pin 0. See 4.5.5	
P1	4	10	I	User configurable input pin 1. See 4.5.5	
P2	5	11	I	User configurable input pin 2. See 4.5.5	
P3	7	13	I	User configurable input pin 3. See 4.5.5	
VDD	20	4	Р	Core voltage supply pin. See 4.5.2	
VDDOA	11	18	Р	Output voltage supply pin for CLK0 and CLK1. See 4.5.2	
VDDOB	10	16	Р	Output voltage supply pin for CLK2 and CLK3. See 4.5.2	
VDDOC	18	2	Р	Output voltage supply pin for CLK4 and CLK5. See 4.5.2	
VDDOD	14	22	Р	Output voltage supply pin for CLK6 and CLK7. See 4.5.2	
GND	Center Pad	5, 8, 17, 19	Р	Ground	





## 6. Pin Descriptions (10-MSOP)

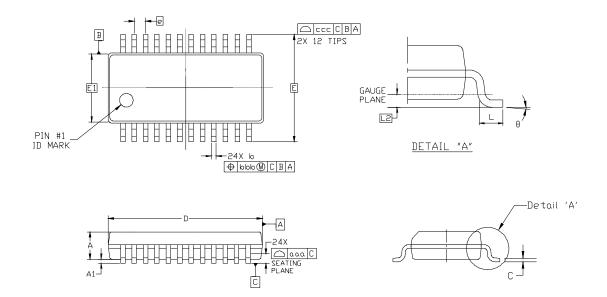
## Si5350C 10-MSOP **Top View**



Pin Name	Pin Number	Pin Type	Function			
	10-MSOP					
XA	2	I	Input pin for external XTAL			
XB	3	I	Input pin for external XTAL			
CLKIN	5	ĺ	External reference clock input			
CLK0	10	0	Output clock 0			
CLK1	9	0	Output clock 1			
CLK2	6	0	Output clock 2			
P0	4	I	User configurable input pin 0. See 4.5.5			
VDD	1	Р	Core voltage supply pin. See 4.5.2			
VDDO	7	Р	Output voltage supply pin for CLK0, CLK1, and CLK2. See 4.5.2			
GND	8	Р	Ground			
Note: Pin Ty	Note: Pin Types: I = Input, O = Output, P = Power					



## 7. Package Outline (24-Pin QSOP)



**Table 10. 24-QSOP Package Dimensions** 

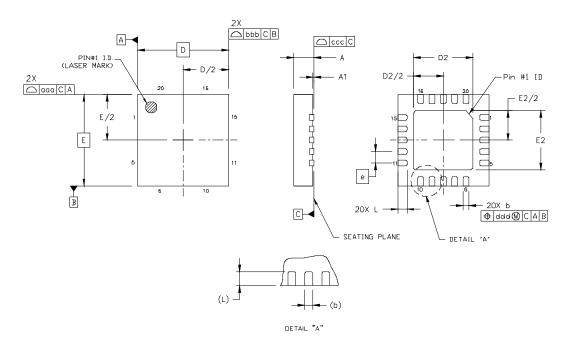
Dimension	Min	Nom	Max
А	_	_	1.75
A1	0.10	_	0.25
b	0.19	_	0.30
С	0.15	_	0.25
D	8.55	8.65	8.75
Е	6.00 BSC		
E1	3.81	3.90	3.99
е	0.635 BSC		
L	0.40	_	1.27
L2	0.25 BSC		
q	0	_	8
aaa	0.10		
bbb	0.17		
CCC	0.10		

#### Notes:

- $\textbf{1.} \ \ \text{All dimensions shown are in millimeters (mm) unless otherwise noted}.$
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. This drawing conforms to the JEDEC Solid State Outline MO-137, Variation C
- **4.** Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



## 8. Package Outline (20-Pin QFN)



**Table 11. Package Dimensions** 

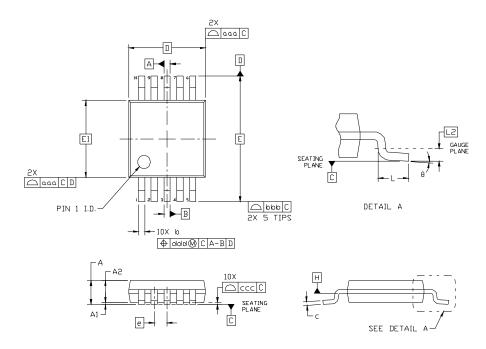
Dimension	Min	Nom	Max
A	0.80	0.85	0.90
A1	0.00	0.02	0.05
b	0.18	0.25	0.30
D	4.00 BSC		
D2	2.65	2.70	2.75
е	0.50 BSC		
E	4.00 BSC		
E2	2.65	2.70	2.75
L	0.30	0.40	0.50
aaa			0.10
bbb			0.10
ccc			0.08
ddd			0.10
eee			0.10

#### Notes:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. This drawing conforms to the JEDEC Outline MO-220, variation VGGD-8.
- **4.** Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

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## 8.1. Package Outline (10-Pin MSOP)



**Table 12. 24-QSOP Package Dimensions** 

Dimension	Min	Nom	Max
А	_	_	1.10
A1	0.00	_	0.15
A2	0.75	0.85	0.95
b	0.17	_	0.33
С	0.08	_	0.23
D	3.00 BSC		
E	4.90 BSC		
E1	3.00 BSC		
е	0.50 BSC		
L	0.40	0.60	0.80
L2	0.25 BSC		
q	0	_	8
aaa	_	_	0.20
bbb	_	_	0.25
ccc	_	_	0.10
ddd	_	_	0.08

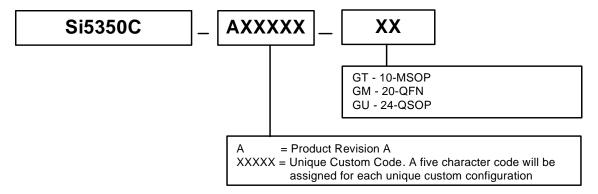
### Notes:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. This drawing conforms to the JEDEC Solid State Outline MO-137, Variation C
- **4.** Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



## 9. Ordering Information

Factory-programmed Si5350C devices can be requested using the ClockBuilder web-based utility available at: www.silabs.com/ClockBuilder. A unique part number is assigned to each custom configuration as indicated in Figure 8.



**Figure 8. Custom Clock Part Numbers** 

A development kit containing ClockBuilder Desktop software and hardware enable easy field programming of blank Si5350C devices for instances when rapid prototyping is required. Note that the Si5350C can only be field-programmed using the development kit. In addition to field programming, this development kit supports simplified device evaluation of any Si5350C device. The orderable part numbers for the development kits and blank Si5350C devices to be used for field programming are provided in Figure 9 and Figure 10, respectively.

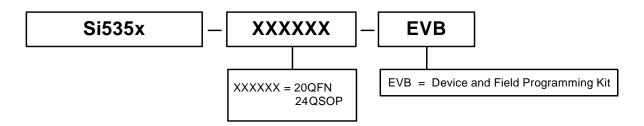


Figure 9. Development Kit Part Numbers

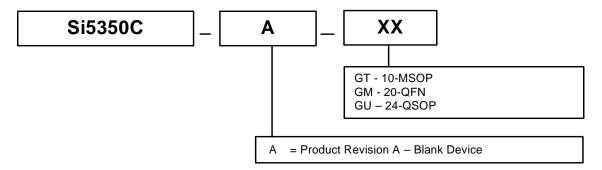


Figure 10. Blank Device Part Numbers



Notes:



## Si5350C

## **CONTACT INFORMATION**

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